

MH188 Hall-effect sensor is a temperature stable, stress-resistant sensor. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

MH188 includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, Advanced DMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

This device requires the presence of both south and north polarity magnetic fields for operation. In the presence of a south polarity field of sufficient strength, the device output sensor on, and only switches off when a north polarity field of sufficient strength is present.

MH188 is rated for operation between the ambient temperatures −40°C and 85°C for the E temperature range, and −40°C to 125°C for the K temperature range. The two package styles available provide magnetically optimized solutions for most applications. Package SO is an SOT-23, a miniature low-profile surface-mount package, while package UA is a three-lead ultra mini SIP for through-hole mounting.

Packages is Halogen Free standard and which have been verified by third party lab.

### Features and Benefits

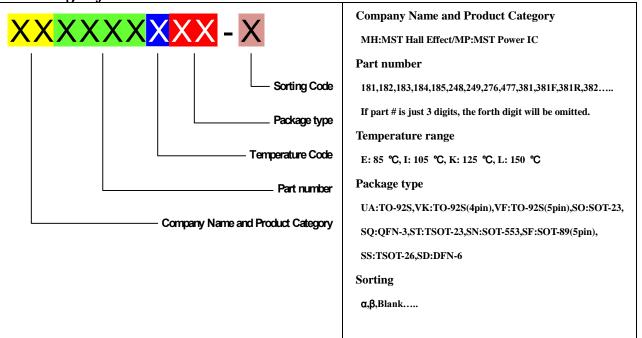
- DMOS Hall IC Technology.
- Reverse bias protection on power supply pin.
- Chopper stabilized amplifier stage.
- Optimized for BLDC motor applications.
- Reliable and low shifting on high Temp condition.
- Good ESD Protection.
- 100% tested at 125 °C for K.
- Custom sensitivity / Temperature selection are available.

#### **Applications**

- High temperature Fan motor
- 3 phase BLDC motor application
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting
- Solid-State Switch
- Linear Position Detection
- Angular Position Detection
- Proximity Detection
- High ESD Capability



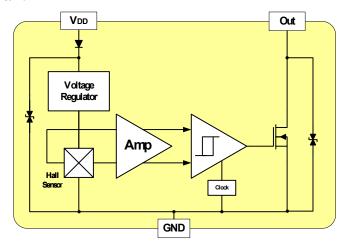
### **Ordering Information**



Part No.	Temperature Suffix	Package Type
MH188KUA	$K (-40^{\circ}C \text{ to} + 125^{\circ}C)$	UA (TO-92S)
MH188KSO	$K (-40^{\circ}C \text{ to} + 125^{\circ}C)$	SO (SOT-23)
MH188EUA	$E (-40^{\circ}C \text{ to} + 85^{\circ}C)$	UA (TO-92S)
MH188ESO	E $(-40^{\circ}\text{C to} + 85^{\circ}\text{C})$	SO (SOT-23)

KUA spec is using in industrial and automotive application. Special Hot Testing is utilized.

### Functional Diagram





**Absolute Maximum Ratings** At (Ta=25 °C)

Characteristics			Values	Unit
Supply voltage, (VDD)			28	V
Output Voltage,(Vout)			28	V
Reverse voltage, (VDD)			-28/-0.3	V
Output current, (Iout)			50	mA
One of the Transport Property	(T-)	"E" version	-40 to +85	°C
Operating Temperature Range,	(1a)	"K" version	-40 to +125	°C
Storage temperature range, ( <i>Ts</i> )			-65 to +150	$\mathcal{C}$
Maximum Junction Temp,( <i>Tj</i> )			150	$\mathcal{C}$
Thermal Resistance	$( heta_{ja})$	UA/SO	206 / 543	°C/W
	$(\theta_{jc})$ UA / SO		148 / 410	°C/W
Package Power Dissipation, $(P_D)$ UA/SO			606 / 230	mW

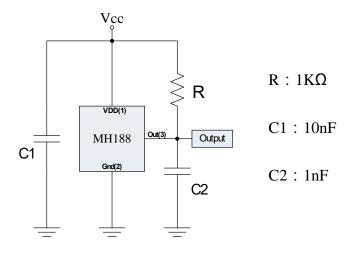
 $\textit{Note: Do not apply reverse voltage to $V_{DD}$ and $V_{OUT}$ Pin, It may be caused for Miss function or damaged device.}$ 

### **Electrical Specifications**

DC Operating Parameters:  $T_A=+25$  °C,  $V_{DD}=12V$ 

Parameters	<b>Test Conditions</b>	Min	Тур	Max	Units
Supply Voltage, $(V_{DD})$	Operating	2.5		26.0	V
Supply Current,( <i>I</i> <sub>DD</sub> )	B <bop< td=""><td></td><td></td><td>5.0</td><td>mA</td></bop<>			5.0	mA
Output Saturation Voltage, (Vsat)	Iout=20mA,B>BOP			400.0	mV
Output Leakage Current, (Ioff)	IOFF B <brp, vout="12V&lt;/td"><td></td><td></td><td>10.0</td><td>uA</td></brp,>			10.0	uA
Internal Oscillator Chopper Frequency,(fosc)			69		kHz
Output Rise Time, $(T_R)$	RL=1.1K $\Omega$ , CL=20pF		0.04	0.45	uS
Output Fall Time, ( <i>T<sub>F</sub></i> )	RL=820Ω; CL=20pF		0.18	0.45	uS
Electro-Static Discharge	HBM	4			KV
Operate Point,(BoP)	UA(SO)	5(-25)		25(-5)	Gauss
Release Point,(BRP)	UA(SO)	-25(5)		-5(25)	Gauss
Hysteresis,(BHYS)			30		Gauss

## Typical application circuit

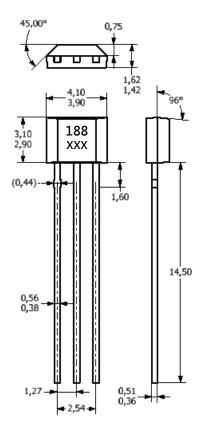




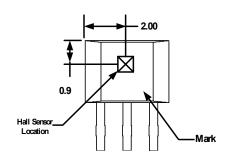
## Sensor Location, Package Dimension and Marking

## MH188 Package

#### **UA Package**



### **Hall Chip location**



#### **NOTES:**

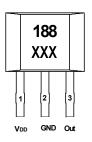
- 1).Controlling dimension: mm
- 2).Leads must be free of flash and plating voids
- Do not bend leads within 1 mm of lead to package interface.
- 4).PINOUT:

Pin 1 VDD

Pin 2 GND

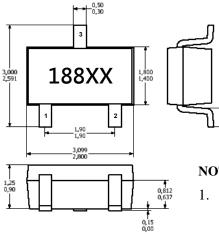
Pin 3 Output

# Output Pin Assignment (Top view)

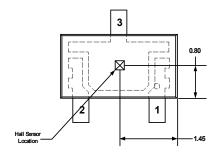


## SO Package

(Top View)



# Hall Plate Chip Location (Bottom view)



### NOTES:

1. PINOUT (See Top View at left :)

Pin 1 V<sub>DD</sub>

Pin 2 Output

Pin 3 GND

- 2. Controlling dimension: mm
- 3. Lead thickness after solder plating will be 0.254mm maximum

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